L	Hits	Search Text	DB	Time stamp
Number		• •	USPAT;	2002/09/19
l	25764	degass\$	US-PGPUB	19:27
			USPAT;	2002/09/19
2	135238	impedance	US-PGPUB	19:27
			USPAT;	2002/09/19
3	592	degass\$ and impedance	US-PGPUB	19:27
			•	2002/09/19
4	419405	semiconductor integrated adj circuit ic	USPAT; US-PGPUB	19:28
				2002/09/19
5	186	(degass\$ and impedance) and	USPAT;	19:28
		(semiconductor integrated adj circuit ic)	US-PGPUB	2002/09/19
6	219099	mesh	USPAT;	
			US-PGPUB	21:14
7	3765	degass\$ and mesh	USPAT;	2002/09/19
			US-PGPUB	21:14
3	466	(degass\$ and mesh) and (semiconductor	USPAT;	2002/09/19
		integrated adj circuit ic)	US-PGPUB	21:14
•	413191	match\$	USPAT;	2002/09/19
			US-PGPUB	21:15
10	82	((degass\$ and mesh) and (semiconductor	USPAT;	2002/09/19
		integrated adj circuit ic)) and match\$	US-PGPUB	21:17
11	995	conductive adj mesh	USPAT;	2002/09/19
11			US-PGPUB	21:17
12	4	(conductive adj mesh) and degass\$	USPAT;	2002/09/19
	_	(Contactive and moon) and angular	US-PGPUB	21:18
-	11615	degassing	USPAT;	2002/09/18
	11013	ueyassing	US-PGPUB	23:01
	0	20020003049.URPN.	USPAT	2002/09/18
•	0	20020003049.0KFK.		23:03
		20040052820 HPPN	USPAT	2002/09/18
•	0	20010052829.URPN.	COLAI	23:04
		W 40 4 T T 00 W W C 4 E 4 T T W W C 9 E 4 E 2 A W	USPAT	2002/09/18
-	10	("4617730" "5615477" "5854534"	USPAI	23:08
		"5883335" "5994771" "6051867"		23:00
		"6107109" "6114019" "6229209"		
		"6239495").PN.		0000/00/40
-	6		USPAT	2002/09/18
		"5519176" "5841075" "6184477").PN.		23:11
•	1	"6045927".PN.	USPAT	2002/09/19
				13:01
-	72	(outgassing degassing) adj (holes	USPAT;	2002/09/19
		apertures)	US-PGPUB	13:08
-	55	•	USPAT;	2002/09/19
			US-PGPUB	13:05
_	17	((outgassing degassing) adj (holes	USPAT;	2002/09/19
-		apertures)) not (degassing adj holes)	US-PGPUB	13:06
	82		USPAT;	2002/09/19
•	62	degassy lieur (livie aberraie)	US-PGPUB	13:07
	1	(degass\$ near (hole aperture)) not	USPAT;	2002/09/19
-	16		US-PGPUB	13:08
		(((outgassing degassing) adj (holes	03-FGF0B	13.33
		apertures)) (degassing adj holes))		

	1049	(outgas\$ degas\$) with (hole aperture)	EPO; JPO;	2002/09/19
-	1049	(varyasy acyasy) with (note apertale)	DERWENT;	13:20
			IBM TDB	
	1130221	semiconductor integrated adj circuit ic	EPO: JPO:	2002/09/19
-	1130221	Seniiconductor integrated day on our io	DERWENT;	13:22
			IBM TDB	
_	77	((outgas\$ degas\$) with (hole aperture)) and	EPO; JPO;	2002/09/19
-	1	(semiconductor integrated adj circuit ic)	DERWENT:	13:12
		(Semiconductor integrated day on our roy	IBM_TDB	
_	3846777	@pd>19990901	EPO; JPO;	2002/09/19
_	3040777	epur ioooooo.	DERWENT;	13:14
			IBM TDB	
	54	(((outgas\$ degas\$) with (hole aperture)) and	EPO; JPO;	2002/09/19
		(semiconductor integrated adj circuit ic))	DERWENT;	13:14
		not @pd>19990901	IBM TDB	
-	641	(outgas\$ degas\$) with (hole aperture)	USPAT:	2002/09/19
	-	(onigate angust) man (more aperime),	US-PGPUB	13:21
_	569	((outgas\$ degas\$) with (hole aperture)) not	USPAT;	2002/09/19
		(((outgassing degassing) adj (holes	US-PGPUB	13:22
		apertures)) (degassing adj holes))		
_	135	(((outgas\$ degas\$) with (hole aperture)) not	USPAT:	2002/09/19
_	155	(((outgassing degassing) adj (holes	US-PGPUB	19:27
		apertures)) (degassing adj holes))) and		10121
		(semiconductor integrated adj circuit ic)		
_	6	("5706178" "5796163" "5875102"	USPAT	2002/09/19
		"5936848" "6028366" "6268568").PN.		13:25